2SB0789, 2SB0789A (2SB789, 2SB789A)

Silicon PNP epitaxial planar type

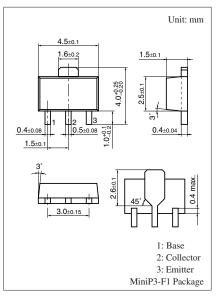
For low-frequency driver amplification

Features

- \bullet High collector-emitter voltage (Base open) $V_{\mbox{CEO}}$
- \bullet Large collector power dissipation $P_{\rm C}$

Parameter	Symbol	Rating	Unit	
Collector-base voltage	2SB0789	V _{CBO}	-100	V
(Emitter open)	2SB0789A		-120	
Collector-emitter voltage	2SB0789	V _{CEO}	-100	V
(Base open)	2SB0789A		-120	
Emitter-base voltage (Coll	V _{EBO}	-5	V	
Collector current	I _C	- 0.5	А	
Peak collector current	I _{CP}	-1	А	
Collector power dissipatio	P _C	1	W	
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	

Absolute Maximum Ratings $T_a = 25^{\circ}C$



Marking Symbol:

- 2SB0789: D
- 2SB0789A: E

Note) *: Print circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion.

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage	2SB0789	V _{CEO}	$I_{C} = -100 \ \mu A, \ I_{B} = 0$	-100			V
(Base open)	2SB0789A			-120			
Emitter-base voltage (Colle	ctor open)	V _{EBO}	$I_E = -10 \ \mu A, \ I_C = 0$	-5			V
Forward current transfer ratio *1		h _{FE1} *2	$V_{CE} = -10 \text{ V}, I_C = -150 \text{ mA}$	90		220	—
		h _{FE2}	$V_{CE} = -5 \text{ V}, I_C = -500 \text{ mA}$	50			
Collector-emitter saturation	voltage *1	V _{CE(sat)}	$I_{C} = -500 \text{ mA}, I_{B} = -50 \text{ mA}$		- 0.2	- 0.6	V
Base-emitter saturation volt	age *1	V _{BE(sat)}	$I_{C} = -500 \text{ mA}, I_{B} = -50 \text{ mA}$		- 0.85	-1.20	V
Transition frequency		f_{T}	$V_{CB} = -10 \text{ V}, I_E = 50 \text{ mA}, f = 200 \text{ MHz}$		120		MHz
Collector output capacitance		C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$			30	pF
(Common base, input open	circuited)						

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

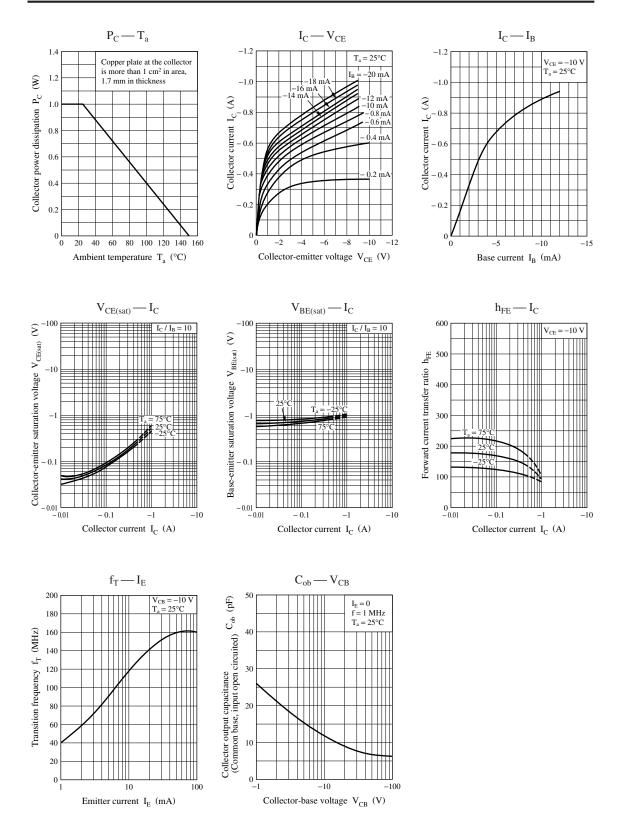
2. *1: Pulse measurement

*2: Rank classification

Rank	Q	R		
h _{FE1}	90 to 155	130 to 220		

Note) The part number in the parenthesis shows conventional part number.

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